NSN 5961-01-171-1969

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View Online at https://aerobasegroup.com/nsn/5961-01-171-1969 **Inclosure Material:** Plastic and metal **Overall Length:** 0.705 inches **Terminal Length:** 0.381 inches **Overall Height:** 0.546 inches **Overall Width:** 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 80.0 collector to emitter voltage, dc with base short-circuited to emitter and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: